

We Claim:

1. A thermoelectric module comprised of:
 - A) a plurality of n-legs comprised of very thin alternating layers of silicon and silicon carbide; and
 - B) a plurality of p-legs,; said p-legs and said n-legs being electrically connected to produce said thermoelectric module.
2. A thermoelectric module as in Claim 1 wherein said p-legs comprise very thin alternating layers of boron carbide.
3. A thermoelectric module as in Claim 2 wherein said very thin alternating layers of boron carbide comprise two different stoichiometric forms of boron carbide.
4. A thermoelectric module as in Claim 3 wherein said very thin alternating layers of boron carbide are alternating layers of B_4C and B_9C .
5. A thermoelectric module as in Claim 2, wherein said plurality of n-legs is comprised of a plurality of very thin alternating layers of silicon and silicon-carbide and said very thin alternating layers of boron carbide are alternating layers of B_4C and B_9C .
6. A thermoelectric module as in Claim 1 wherein said alternating layers are deposited on a substrate.
7. A thermoelectric module as in Claim 6 wherein said substrate is silicon.
8. A thermoelectric module as in Claim 6 wherein said substrate is silicon film.
9. A thermoelectric module as in Claim 6 wherein said substrate is a polyimide substrate.
10. A thermoelectric element as in Claim 9, wherein said polyimide substrate is Kapton®.
11. A thermoelectric element as in Claim 10, wherein said polyimide substrate is Kapton® film.
12. A thermoelectric element as in Claim 1, wherein said very thin alternating layers are each less than 100nm thick.
13. A thermoelectric element as in Claim 1 whereir said very thin alternating layers are each about 10 nm thick.

14. A thermoelectric element as in Claim 9 wherein said plurality of very thin alternating layers is at least 1250 layers.

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